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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## 2SK2730

# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1028-0300

(Previous: ADE-208-493A)

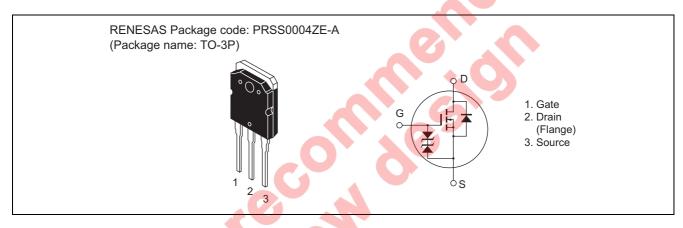
Rev.3.00

Sep 07, 2005

### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- Avalanche ratings

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	500	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	I <sub>D</sub>	25	А
Drain peak current	I <sub>D(pulse)</sub> *1	100	А
Body to drain diode reverse drain current	I <sub>DR</sub>	25	А
Avalanche current	I <sub>AP</sub> *3	25	А
Avalanche energy	E <sub>AR</sub> *3	35	mJ
Channel dissipation	Pch*2	175	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10 $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

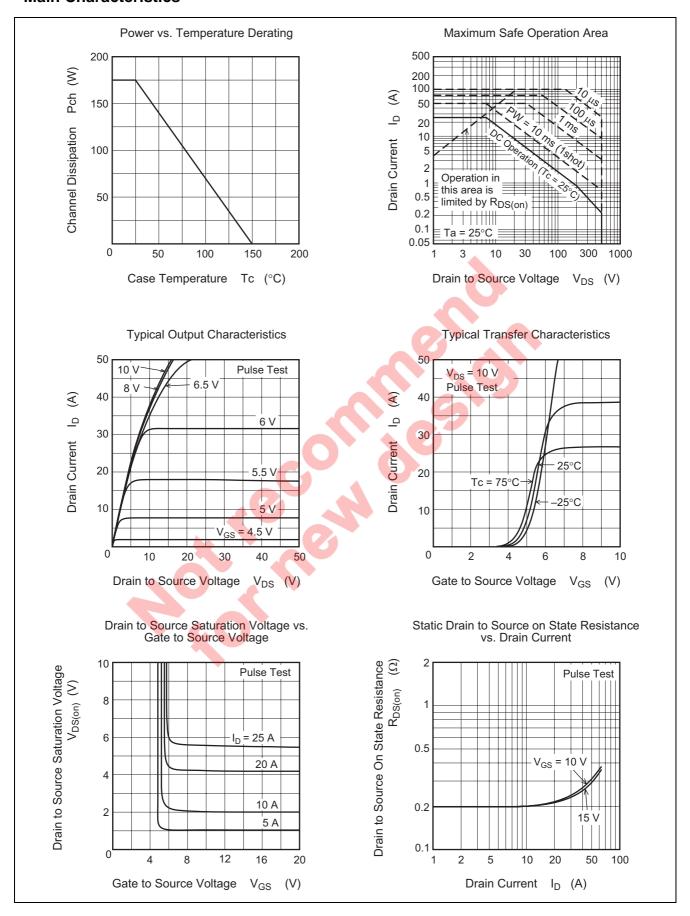
## **Electrical Characteristics**

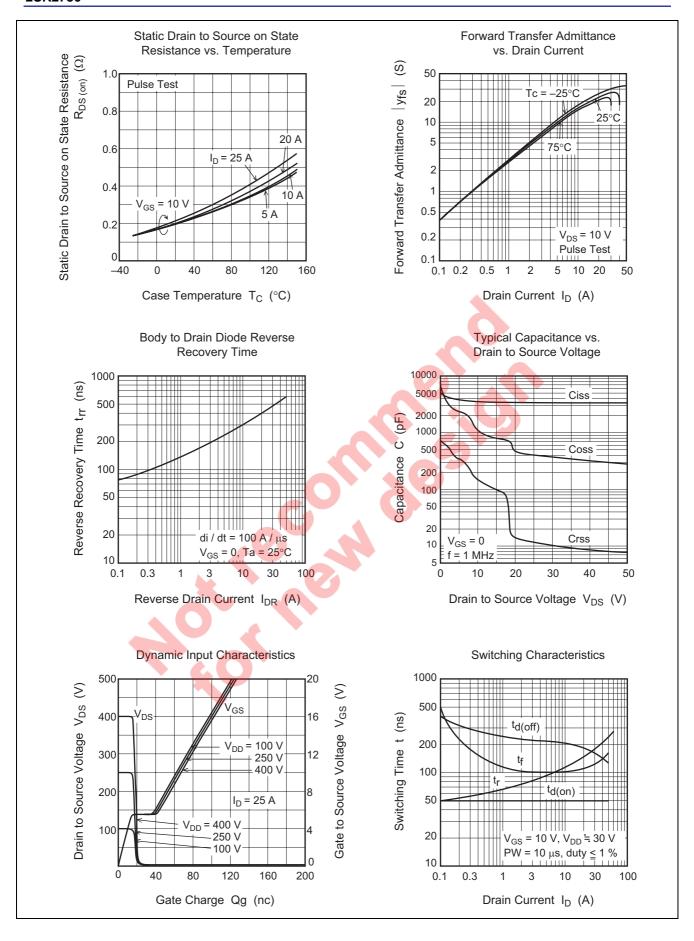
 $(Ta = 25^{\circ}C)$ 

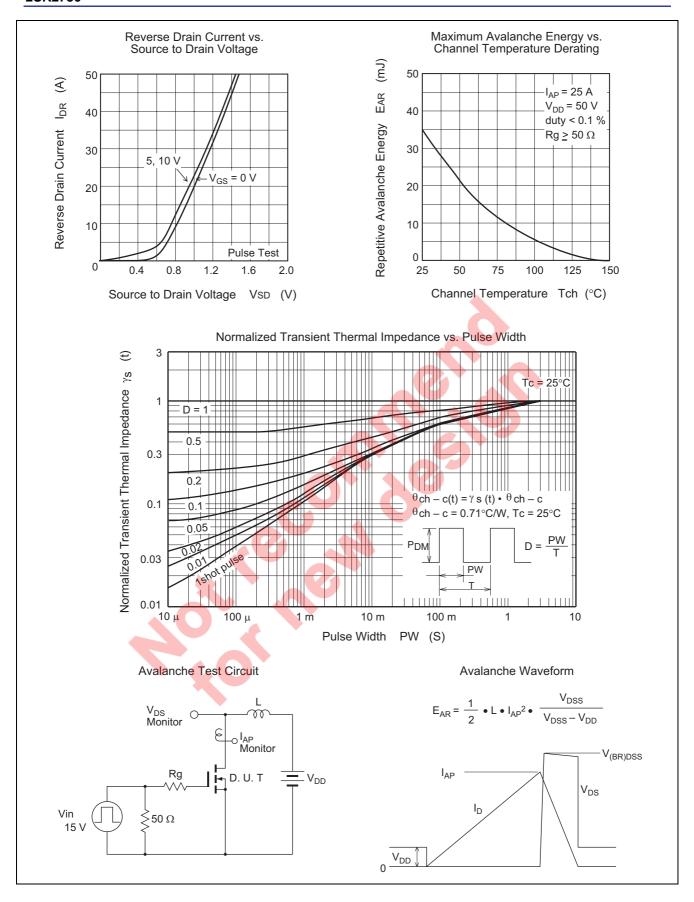
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	500			V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30			V	$I_G = \pm 100 \mu\text{A},  V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_		±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_		10	μΑ	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0
Gate to source cutoff voltage	$V_{GS(off)}$	2.5	<b>Y</b> —	3.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{*4}$
Static drain to source on state	R <sub>DS(on)</sub>		0.2	0.24	Ω	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{*4}$
resistance			•			
Forward transfer admittance	y <sub>fs</sub>	12	20	_	S	$I_D = 15 \text{ A}, V_{DS} = 10 \text{ V}^{*4}$
Input capacitance	Ciss	_	3500	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	-	1000	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	7	150	_	pF	
Total gate charge	Qg		65	_	nc	V <sub>DD</sub> = 400 V, V <sub>GS</sub> = 10 V,
Gate to source charge	Qgs	_	16	_	nc	$I_D = 25 A$
Gate to drain charge	Qgd	_	24	_	nc	
Turn-on delay time	t <sub>d(on)</sub>	_	50	_	ns	$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A},$
Rise time	t <sub>r</sub>	_	140	_	ns	$R_L = 2 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	200	_	ns	
Fall time	t <sub>f</sub>	_	110	_	ns	
Body to drain diode forward voltage	$V_{DF}$	_	1.1	_	V	$I_D = 25 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery	t <sub>rr</sub>	_	450	_	ns	I <sub>F</sub> = 25 A, V <sub>GS</sub> = 0
time						diF/ dt = 100A/ μs

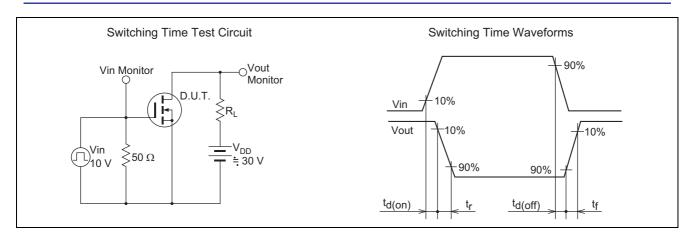
Note: 4. Pulse test

#### **Main Characteristics**



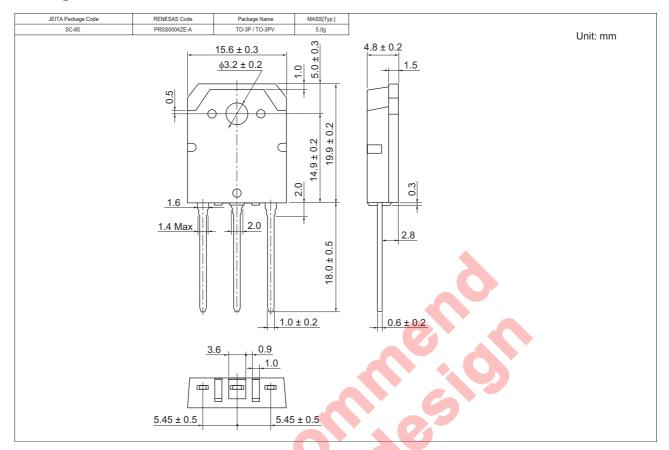








## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
2SK2730-E	360 pcs	Box (Tube)

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